



APT13005S

#### 450V NPN HIGH VOLTAGE POWER TRANSISTOR

#### **Features**

- BV<sub>CEO</sub> > 450V
- BV<sub>CES</sub> > 700V
- BV<sub>EBO</sub> > 9V
- I<sub>C</sub> = 3.2A High Continuous Collector Current
- Lead-Free Finish; RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q100/101/200, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative. https://www.diodes.com/quality/product-definitions/

#### **Mechanical Data**

- Case: ITO220AB (Type BR)
- Case Material: Molded Plastic, "Green" Molding Compound;
   UL Flammability Classification Rating 94V-0
- Terminals: Matte Tin Finish;
   Solderable per MIL-STD-202, Method 208 (3)
- Weight: 1500mg (Approximate)

### **Applications**

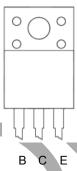
Low Power AC-DC SMPS for:

- Battery Chargers for Mobile Phone / Tablets / Smartphones
- Power Supply for DVD / STB
- LED Lighting

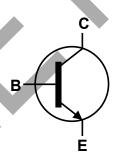
ITO220AB Isolated



Side View



Front Face View
Pin-Out



Device Schematic

### Ordering Information (Note 4)

Product	Package	Marking	Quantity
APT13005STF-G1	ITO220AB	APT13005STF-G1	1000 per Box in Tubes

Notes:

- 1. EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. All applicable RoHS exemptions applied.
- 2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.
- 4. For packaging details, go to our website at http://www.diodes.com/products/packages.html.

## **Marking Information**

### ITO220AB



= Manufacturers' Code Marking
APT13005STF-G1 = Product Type Marking ID
YWW = Date Code Marking
e.g. 012 = Year 2020, Week 12.
8 = Assembly Site Code
XX = Batch Number



### Absolute Maximum Ratings (@T<sub>A</sub> = +25°C, unless otherwise specified.)

Characteristic	Symbol	Value	Unit
Collector-Emitter Voltage (V <sub>BE</sub> = 0V)	V <sub>CES</sub>	700	V
Collector-Emitter Voltage	V <sub>CEO</sub>	450	V
Emitter-Base Voltage	V <sub>EBO</sub>	9	V
Continuous Collector Current	Ic	3.2	Α
Peak Pulse Collector Current	I <sub>CM</sub>	6.4	Α
Continuous Base Current	I <sub>B</sub>	1.6	Α
Peak Pulse Base Current	I <sub>BM</sub>	3.2	A

## Thermal Characteristics ( $@T_A = +25^{\circ}C$ , unless otherwise specified.)

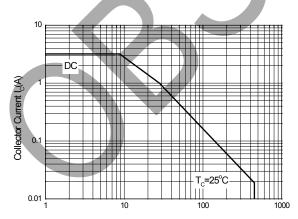
Characteristic	Symbol	Value	Unit
Power Dissipation	Po	28	W
Thermal Resistance, Junction to Case	$R_{ heta JC}$	4.5	°C/W
Operating and Storage Temperature Range	T <sub>J,</sub> T <sub>STG</sub>	-65 to +150	°C

### ESD Ratings (Note 5)

Characteristic	Symbol	Value	Unit	JEDEC Class
Electrostatic Discharge - Human Body Model	ESD HBM	8,000	V	3B
Electrostatic Discharge - Machine Model	ESD MM	400	V	С

Note: 5. Refer to JEDEC specification JESD22-A114 and JESD22-A115.

## Safe Operating Areas (@TA = +25°C, unless otherwise specified.)



Collector-Emitter Clamp Voltage  $V_{\text{CE}}(V)$ 

Safe Operating Areas (ITO220AB Package)



## **Electrical Characteristics** (@T<sub>A</sub> = +25°C, unless otherwise specified.)

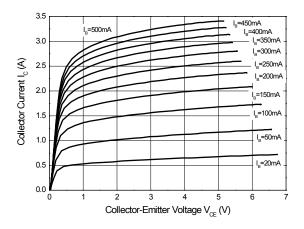
Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition
Collector-Emitter Breakdown Voltage	BV <sub>CES</sub>	700	_	_	V	$I_C = 100 \mu A, V_{BE} = 0 V$
Collector-Emitter Breakdown Voltage	BV <sub>CEO</sub>	450	_	_	V	$I_{C} = 100 \mu A$
Emitter-Base Breakdown Voltage	$BV_{EBO}$	9	_	_	V	I <sub>E</sub> = 100μA
Collector Cutoff Current	I <sub>CEV</sub>	1	_	10	μΑ	V <sub>CE</sub> = 700V, V <sub>BE</sub> = -1.5V
DC Current Transfer Static Ratio (Note 6)	h <sub>FE</sub>	20 11		35 35	1	$I_{C} = 1A, V_{CE} = 5V$ $I_{C} = 2A, V_{CE} = 5V$
Collector-Emitter Saturation Voltage (Note 6)	V <sub>CE(sat)</sub>		_ _ _	0.3 0.6 1.0	V	$I_C = 1A$ , $I_B = 0.2A$ $I_C = 2A$ , $I_B = 0.5A$ $I_C = 3A$ , $I_B = 0.75A$
Base-Emitter Saturation Voltage (Note 6)	V <sub>BE(sat)</sub>			1.2 1.4	>	$I_C = 1A$ , $I_B = 0.2A$ $I_C = 2A$ , $I_B = 0.5A$
Output Capacitance	C <sub>obo</sub>	_	35		pF	V <sub>CB</sub> = 10V, f = 0.1MHz
Transition Frequency	f <sub>t</sub>	4	_		MHz	I <sub>C</sub> = 0.5A, V <sub>CE</sub> = 10V
Turn-on Time with Resistive Load	ton	_	_	0.7		
Storage Time with Resistive Load	ts	_	-4	4.5	μs	$I_C = 2A$ , $V_{CC} = 125V$ , $I_{B1} = -I_{B2} = 0.4A$
Fall Time with Resistive Load	t <sub>f</sub>		-	0.8		1B11B2 - U.4A

Note: 6. Measured under pulsed conditions. Pulse width  $\leq$  300µs. Duty cycle  $\leq$  2%.

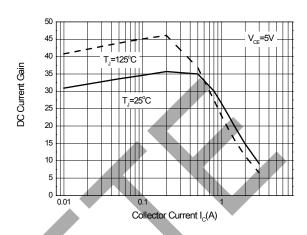




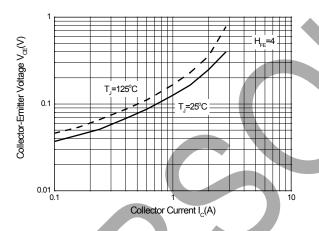
## Typical Electrical Characteristics (@T<sub>A</sub> = +25°C, unless otherwise specified.)



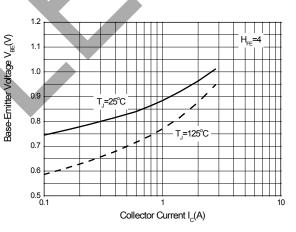
**Static Characteristics** 



**DC Current Gain** 



**Collector-Emitter Saturation Region** 



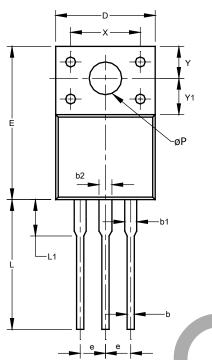
**Base-Emitter Saturation Voltage** 

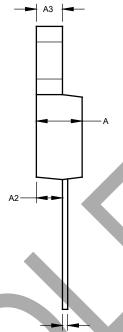


## **Package Outline Dimensions**

Please see http://www.diodes.com/package-outlines.html for the latest version.

#### ITO220AB (TYPE BR)





ITO220AB (TYPE BR)						
Dim	Min	Max	Тур			
Α	<b>A</b> 4.300		-			
A2	2.520	2.920	-			
A3	2.350	2.900	-			
b	0.550	0.900	-			
b1	1.000	1.400	-			
b2	1.100	1.500	-			
C	0.450	0.600	-			
Б	9.70	10.30	-			
Ē	14.70	16.00	-			
е	-	-	2.54			
L	12.50	13.50	-			
L1	2.790	4.500	-			
Х	6.90	7.10	-			
Υ	3.000	3.400	-			
Y1	3.370	3.900	-			
øΡ	3.000	3.550	-			
All Dimensions in mm						

Note: For high voltage applications, the appropriate industry sector guidelines should be considered with regards to voltage spacing between terminals.





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